
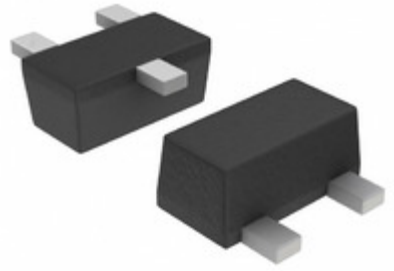



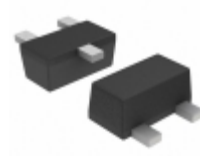




	<h2 style="color: red;">NTE4151PT1G</h2>
	<p>Hersteller-Teilenummer: NTE4151PT1G</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET P-CH 20V 0.76A SC-89</p> <p>Datenblätter:  NTE4151PT1G.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 77712 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTE4151PT1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET P-CH 20V 0.76A SC-89
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	77712 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	SC-89, SOT-490
Supplier Device-Gehäuse	SC-89-3
Verlustleistung (max)	313mW (Tj)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	760mA (Tj)
Rds On (Max) @ Id, Vgs	360 mOhm @ 350mA, 4.5V
VGS (th) (Max) @ Id	450mV @ 250µA
Gate Charge (Qg) (Max) @ Vgs	2.1nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	156pF @ 5V
Antriebsspannung (Max Rds On, Min Rds On)	1.8V, 4.5V
Vgs (Max)	±6V
Verpackung	Tape & Reel (TR)















































NTE4151PT1G ist neu im Original, Suche NTE4151PT1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTE4151PT1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTE4151PT1G: Info@Y-IC.com

Sie können auch interessiert sein:

 NTE4151P1G ON NTE4151P1G ON	 NTE4001NT1G O O SC-89	 NTE858SM NTE NTE858SM NTE	 NTE4153NT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 20V 915MA SC- 89
 NTE2548 ON ON SOT252	 NTE4015B NTE IGBT Modules	 NTE2430 UTG UTG SOT-89	 NTE7002NT1G O O SC-89

heiße Teile

Mehr

 293D106X0020B2TE3	 744043220	 AP7217C-13SPG-13	 ASSR-4111-301E	 B571F-2T
 BL1084-18CY	 CL21B105KOF4PNE	 E3Z-R81H	 FC50S6R5	 GEM318P-ZB2
 LL1608-FH47NK	 LM4902MM/NOP8	 LP2982IM5X-3.8	 LTC4215CUFD-2#PBF	 MG150H2YL2
 MX7225KEWG	 N750CH45KOO	 NTE0303MC	 NTE0303MC-R	 NTE0305MC
 NTE0305MC-R	 NTE0505MC	 NTE0505MC-R	 NTE0506MC	 NTE0509MC
 NTE0515MC	 NTE1205MC	 NTE1205MC-R	 NTE1209MC	 NTE1212MC
 NTE1215MC	 NTE4015B	 NTE4151P1G	 NTE4153NT1G	 NTE858SM
 PM1206STR	 R099OLS04C	 R2475ZC20N	 R3047TC24R	 RC1585DT
 RC82532MDE	 RSR010N10TL	 RT424005	 SI4890BDY-T1	 SKIIP11NAB063T16
 SMF58CA-E3-08	 ST110S14PO	 TC4049BFN-ELP.N.M	 TLP224GA-2	 TPSMA27A

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